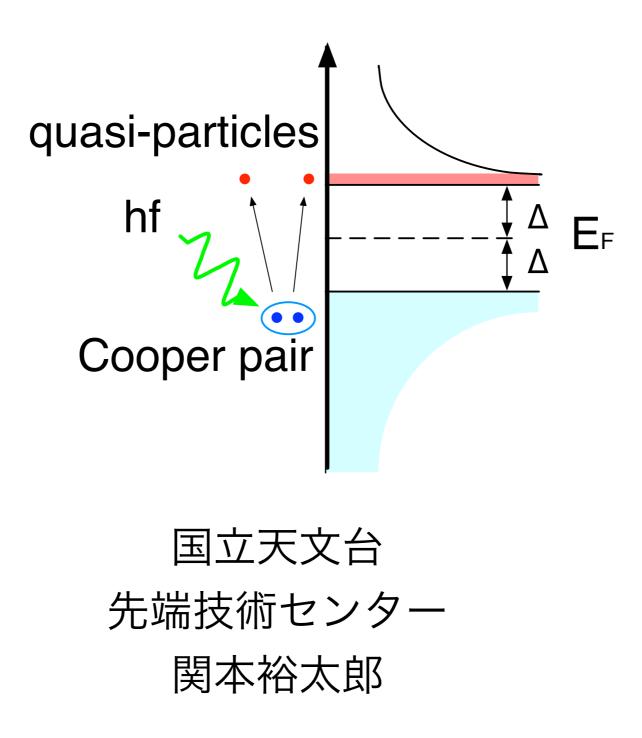
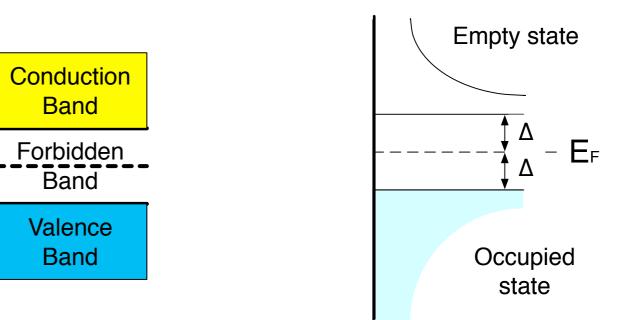
# 可視赤外線の超伝導検出器の紹介

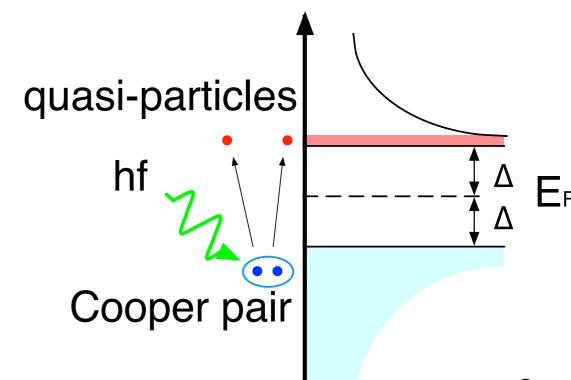


	半導体	超伝導
Bandgap	~ eV	~ meV
運用温度	20 ~ 100 K	100 mK ~ 4 K
時間分解能	~ msec	~ µsec



## 超伝導Cooper pair-breaking検出器

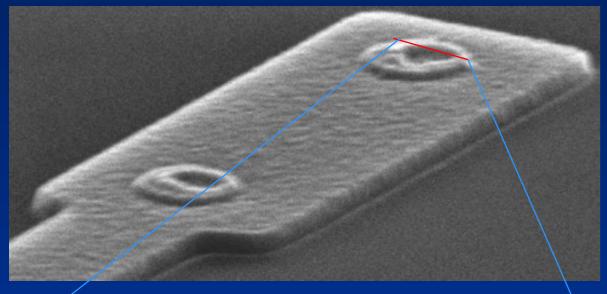
- SIS : Superconductor Insulator Superconductor
- STJ : Superconductive Tunnelling Junction
  - SIS = STJ 準粒子生成によって生じる電流を読み出す。
- MKID : Microwave Kinetic Inductance Detector
  - 準粒子生成によって生じるインダクタンスの変化を読み出す。
- TES: Transition Edge Sensorは、温度を計測するbolometer

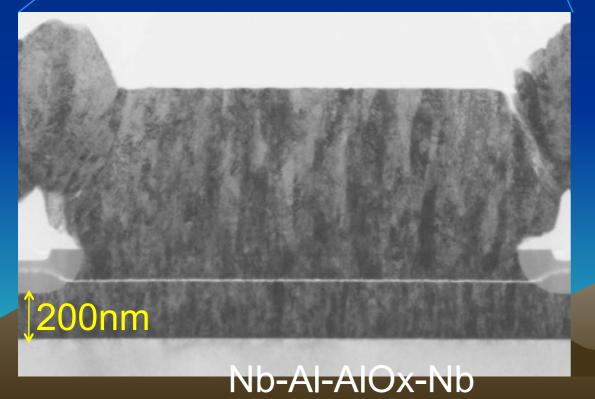


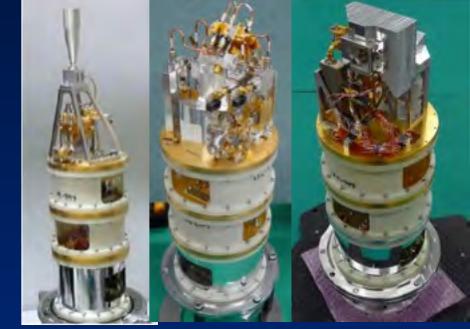
•

# SIS mixer

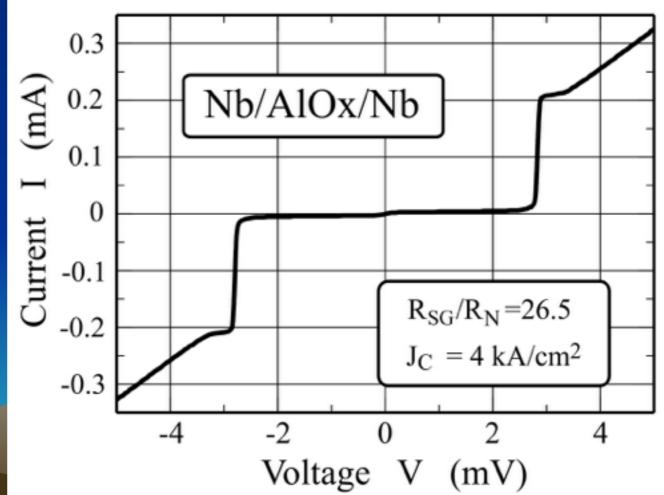
#### T. Tamura et al. 2014 IEEE AS







ALMA Band 4 (125 – 163 GHz) ALMA Band 8 (385 – 500 GHz) ALMA Band 10 (787 – 950 GHz)



### 近赤外線超伝導検出器

Band gapが小さい 2∆~1 meV

・分光が可能

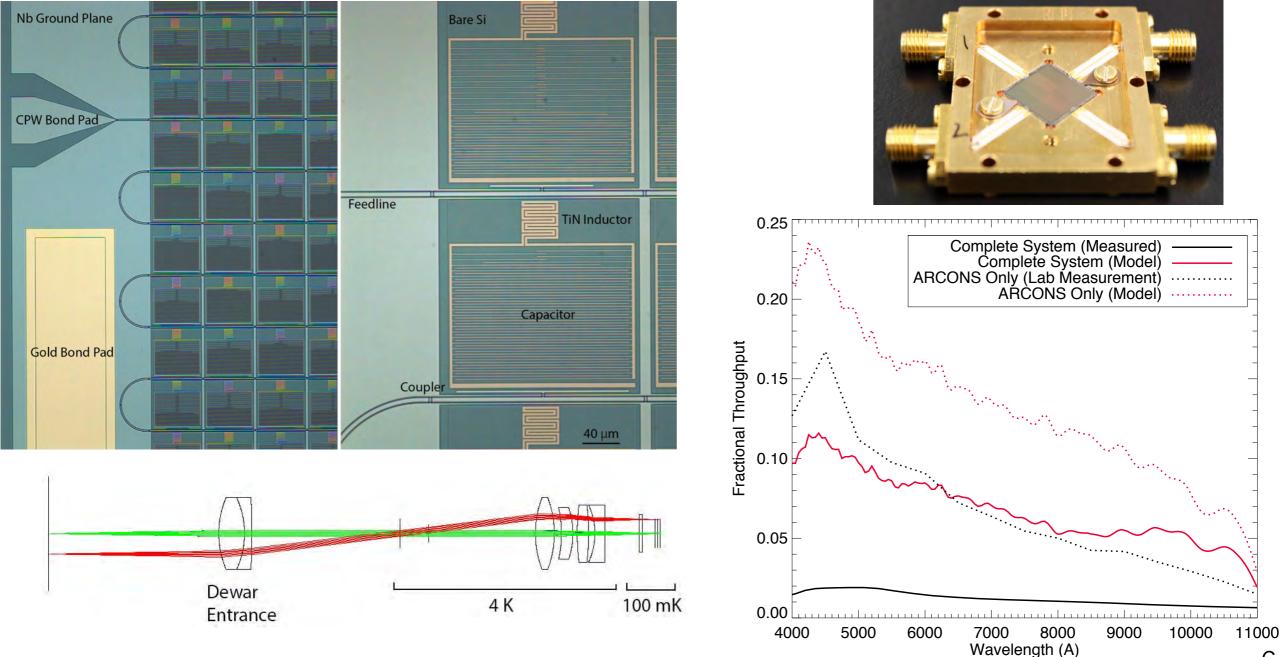
· 配線層 = 超伝導線路

・量子効率を高くできる

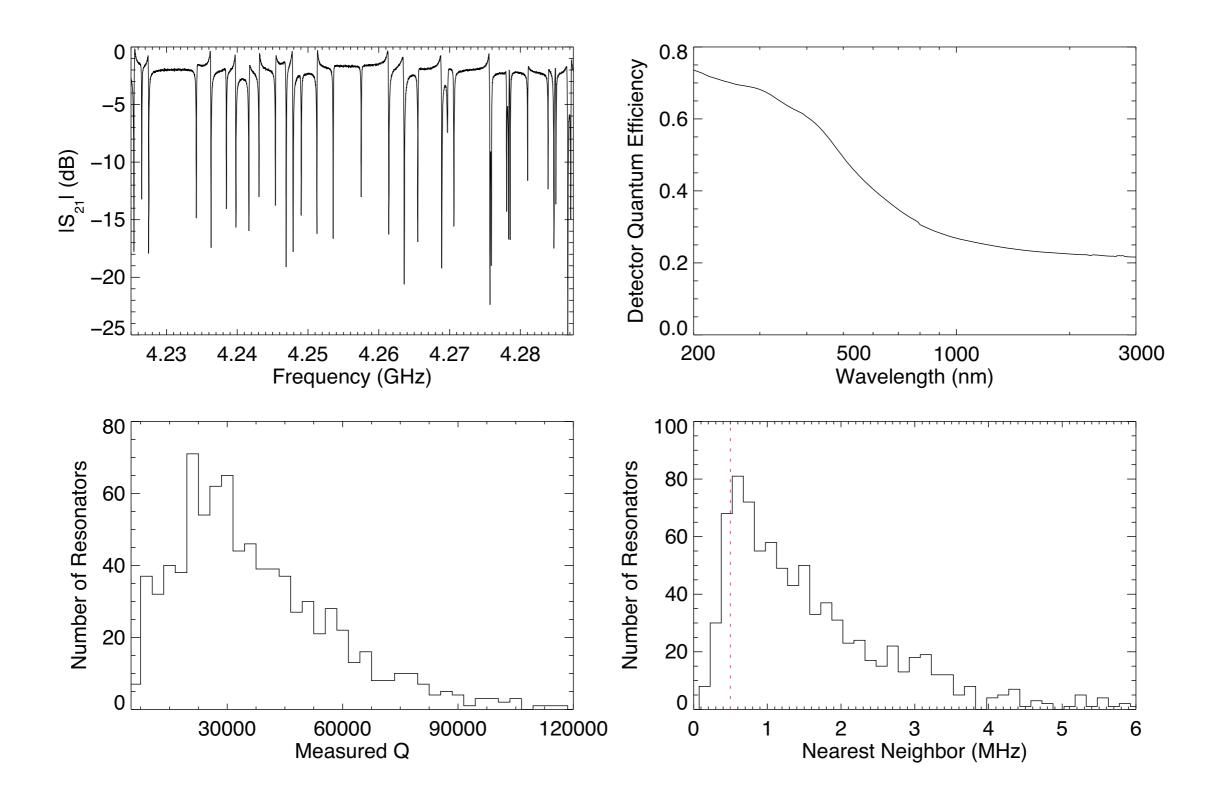
大面積・多ピクセルは難しい

### ARCONS: B. Mazin + 2013 PASP 125, 12

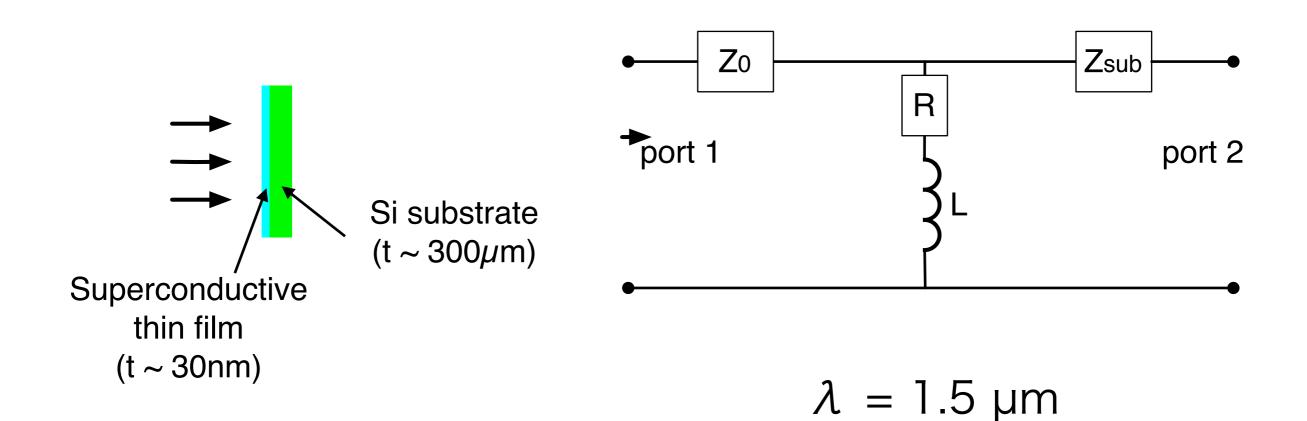
A microlens focuses the light on to the 40×40  $\mu$ m inductor. The MKIDs in ARCONS absorb light directly in the TiN film that comprises the inductor. This TiN has an intrinsic absorption of roughly 70% at 400 nm, and 30% at 1  $\mu$ m. 2024 (44×46) pixel array. Tc is about 800 mK. The surface inductance is a high 25 pH/square. 222×222  $\mu$ m square. The quasiparticle lifetime in our TiN films is 50–100  $\mu$ s. a maximum count rate of approximately 2500 cts/pixel/second.



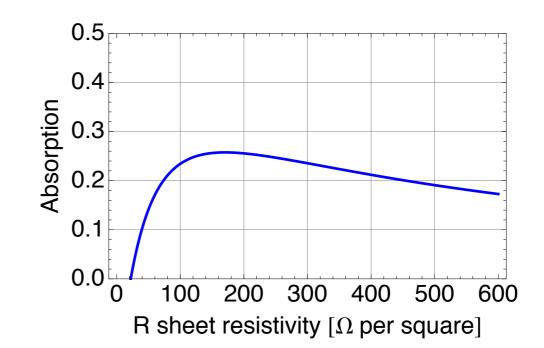
#### B. Mazin + 2012 Optics Express



# **Optical Coupling**

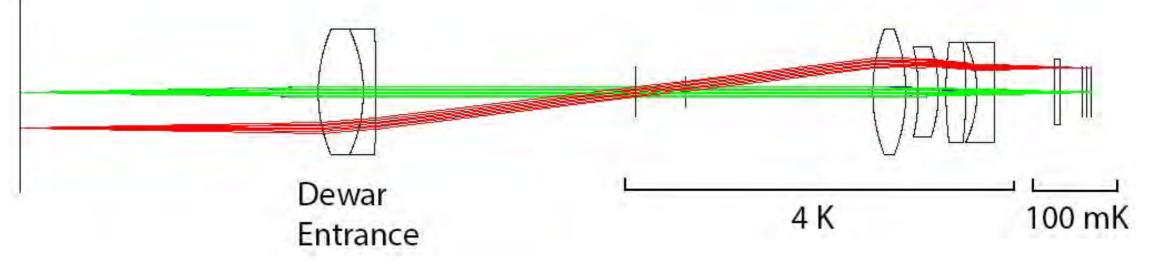






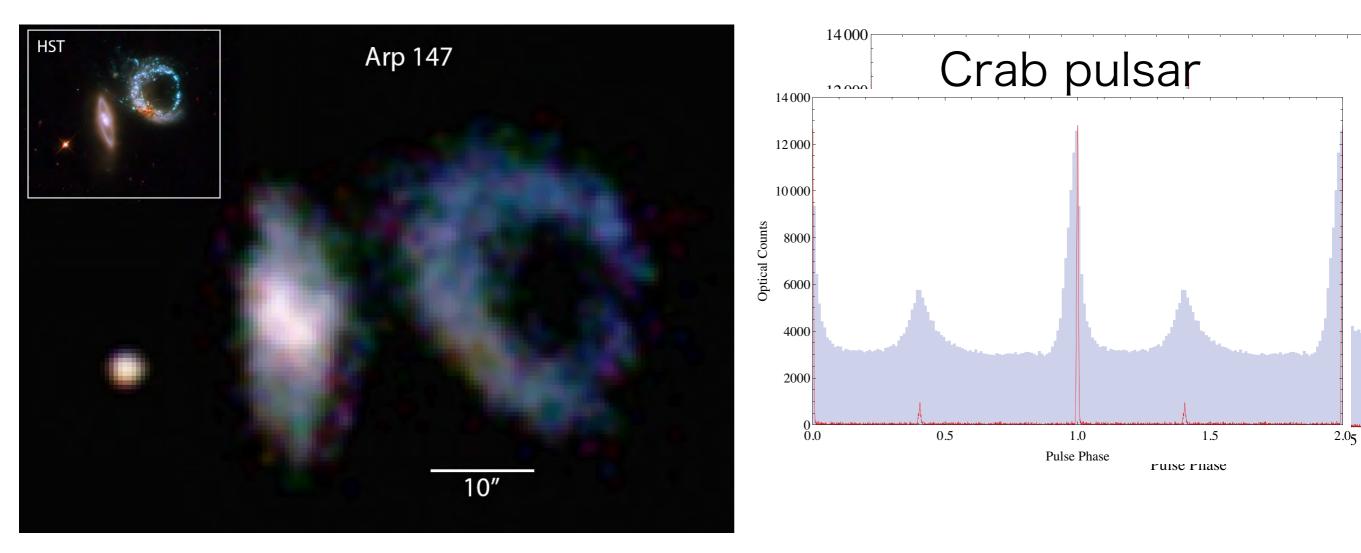


B. A. Mazin,et al. 2013, PASP 125, 1348 "ARCONS: A 2024 Pixel Optical through Near-IR Cryogenic Imaging Spectrophotometer,"

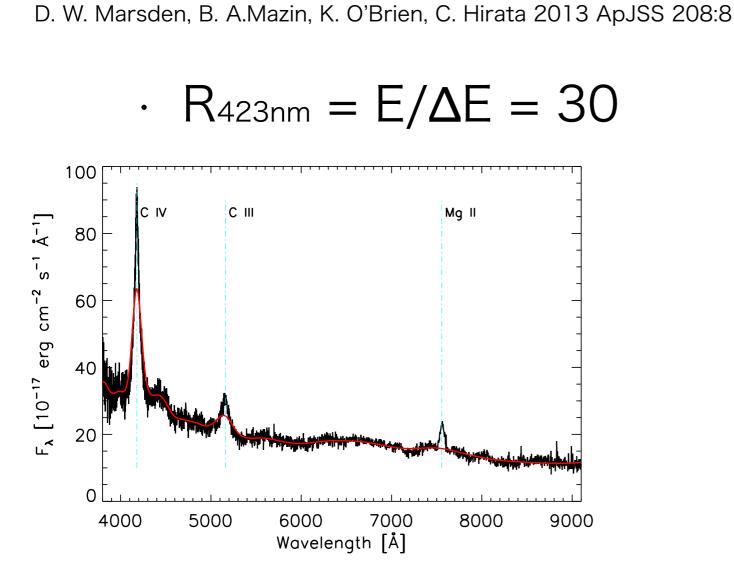


# ARCONS: B. Mazin, et al. 2013 PASP 125,12

ARCONS: Array Camera for Optical to Near-IR Spectrophotometry



#### Palomar 200"

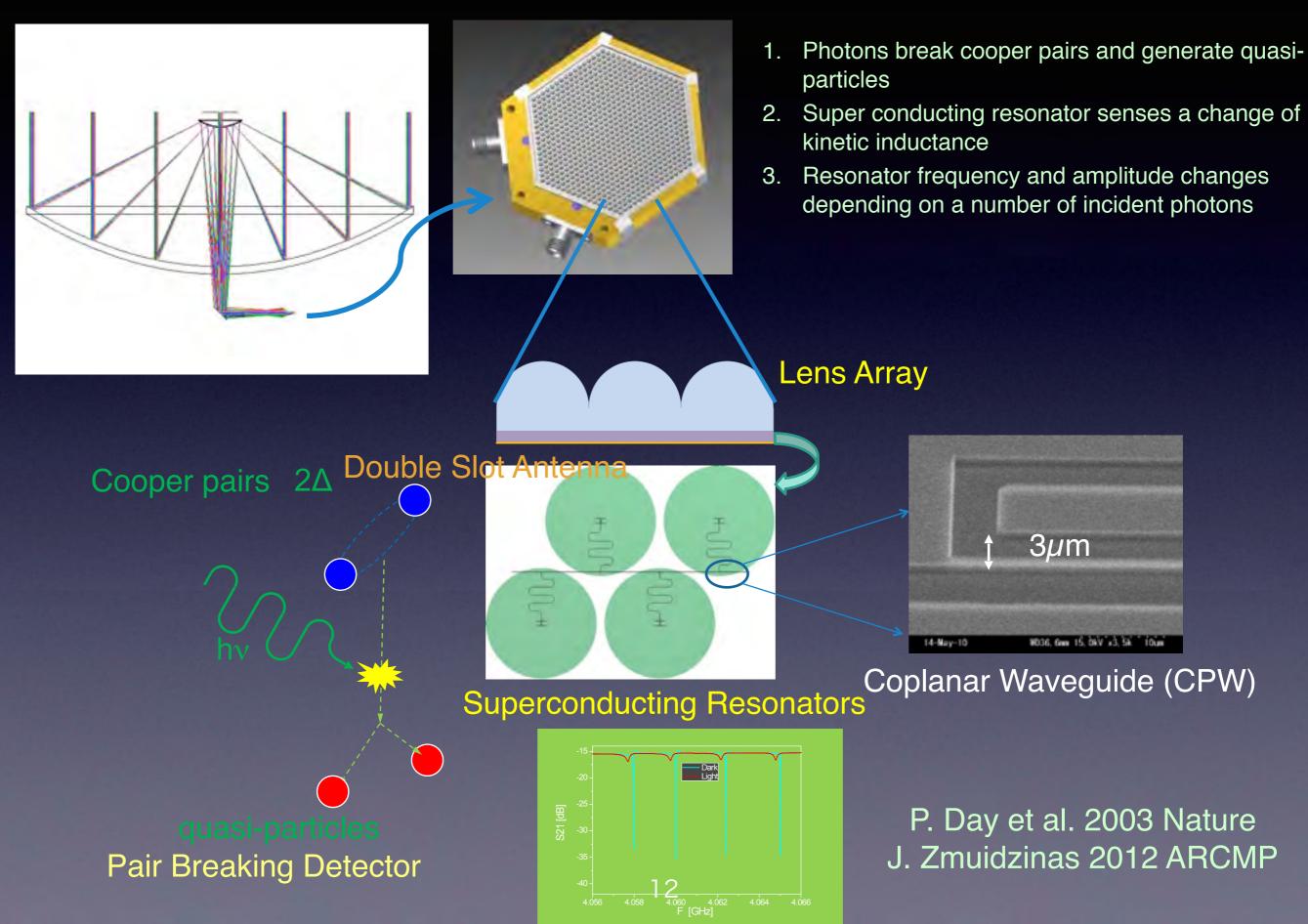


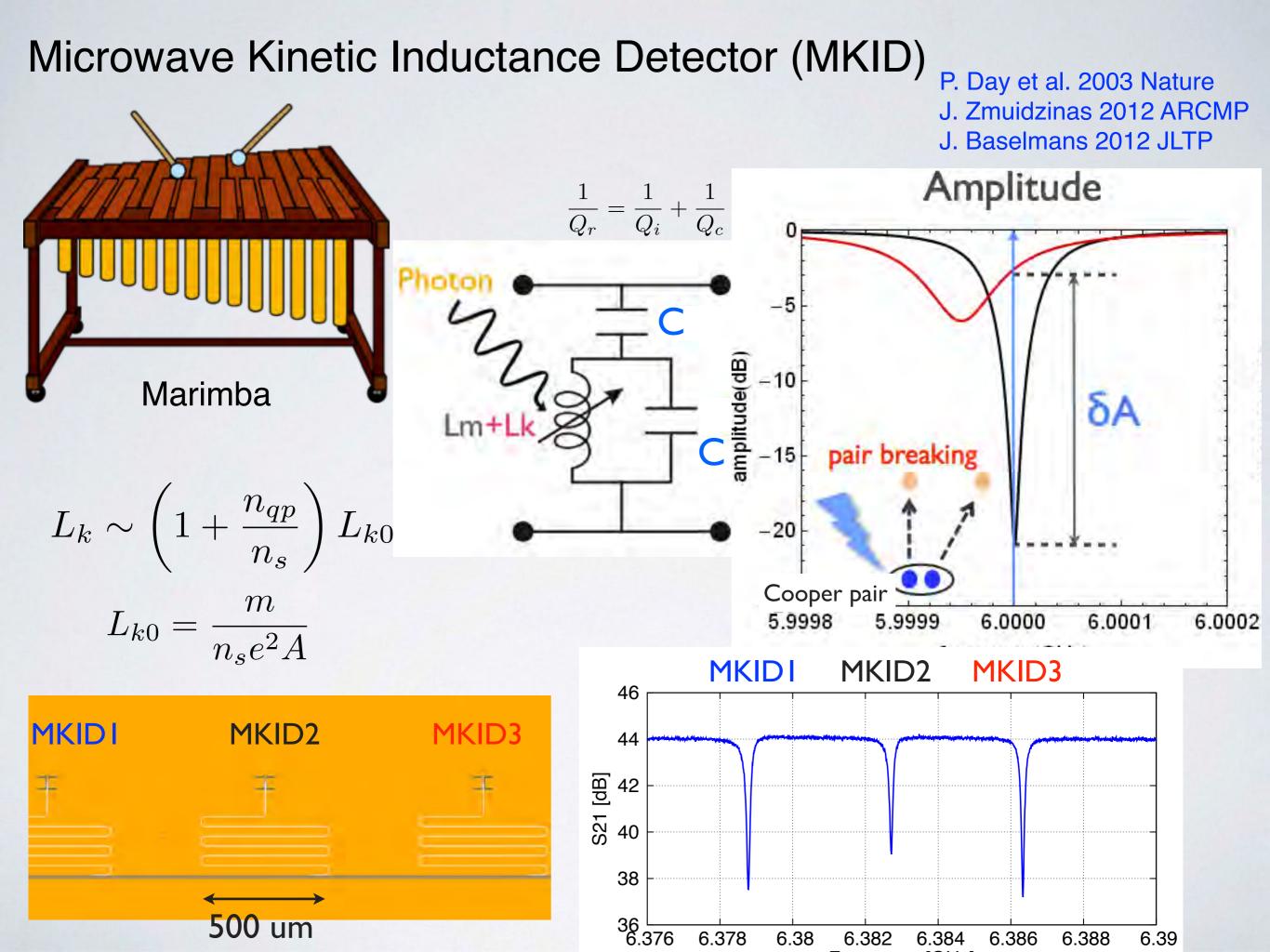
Telescope Primary			/
	Front O ADC	Optic Focal Plane Mask	
0.3	Reimaging Dewar Entra MKID Focal	ance Window	[
110 0.2 0.1 0.0			
0.25 0.20 0.15 0.10 0.05 0.00			
400 600	800 1000 velength [nm]	1200	140

	σ(w_p)	σ(w_a)	σ(Δγ)	σ(Ω_k)
LSST photo-z	0.0382	0.695	0.221	0.0252
Giga-z photo-z	0.0348	0.576	0.168	0.0205

#### Giga-z: A 100,000 OBJECT SUPERCONDUCTING SPECTROPHOTOMETER FOR LSST FOLLOW-UP

#### MKID: Microwave Kinetic Inductance Detector





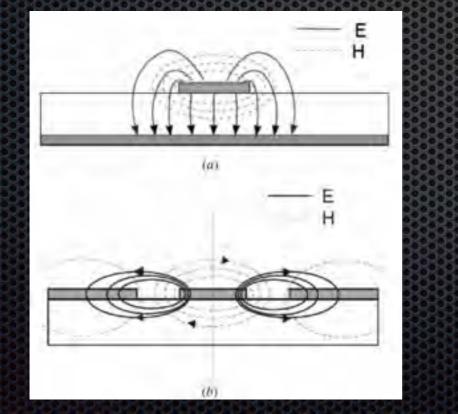
# MKIDの特徴

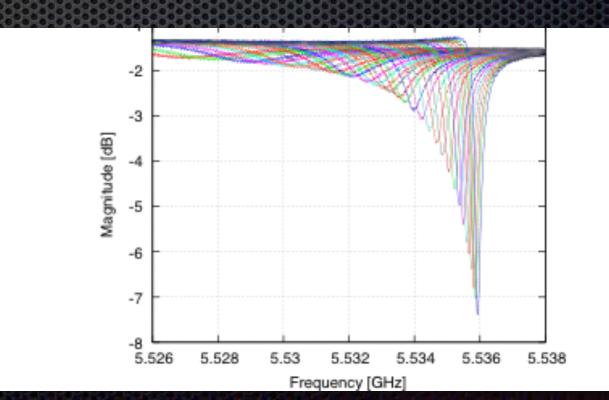
Cooper pair breaking detector
 ミリ波からX線まで
 低雑音 NEP < 5 \* 10^{-18} W/rHz</li>
 広いダイナミックレンジ~10^5

周波数多重化1000素子 with a LNA

<b>j</b>	$\frac{g}{g} = -\frac{1}{g}$	$\overline{h} = 7$	4 GHz	$\times \frac{-c}{1 \text{ K}}$
	materi al	Tc [K]	Tb [K]	<b>f</b> g [GHz]
	Al	1.2	0.24	88
	Nb	9.3	1.9	678
	Ti	0.4	0.08	29
	NbTiN	14	2.8	1026
	TiN	(0.5) -	0.9	330

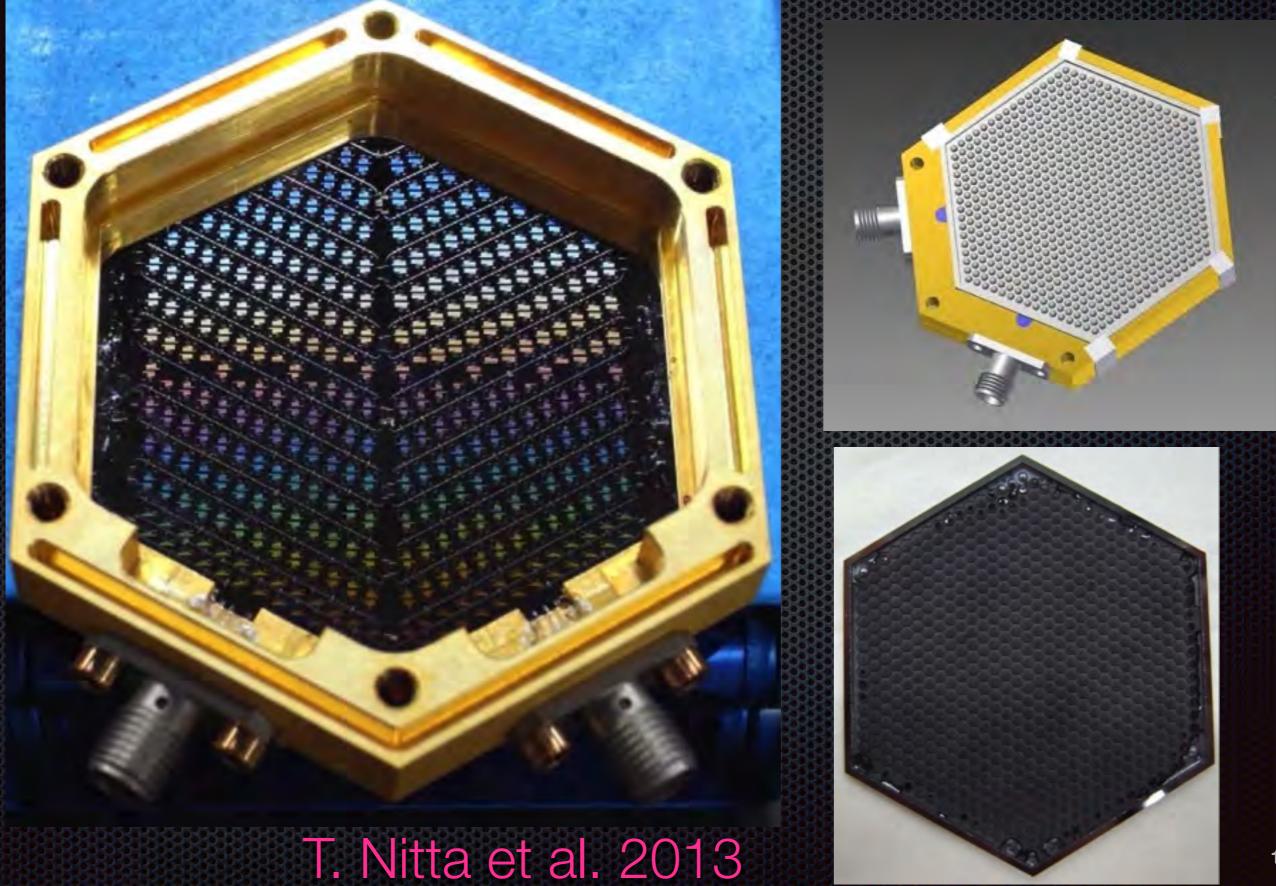
21





 $\mathbf{T}$ 

# 220GHz-700 pixel MKID camera



# Crystal Aluminum on Si wafers

#### Molecular Beam Epitaxy

Al on Si (111) wafer Thickness 160nm Cleaning: BHF + 650 deg. (20 min) Back ground: 2×10^-8 Pa Wafer: 75 deg.

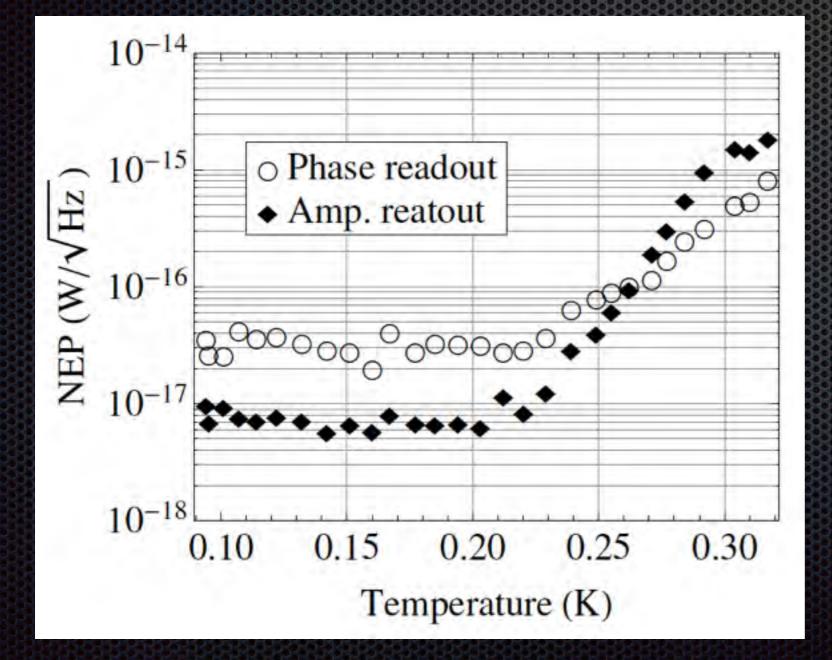
> #3152111) 2M .- 6.RAW 00-004-0787> Aluminum - A 11-027-1402: Second AI (111) 2 H (dea

RHEED

M. Naruse et al. 2012 JLTD "Development of crystal AI MKIDs by molecular

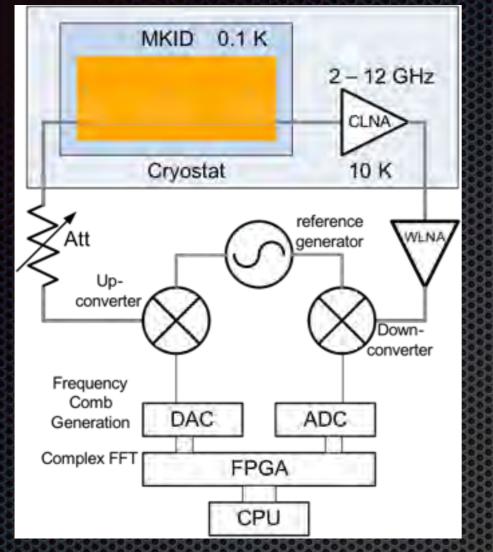
# MKID noise

$$NEP(\omega) = \frac{\sqrt{S_{(\theta,R)}}}{\left[\frac{\eta_q \tau_r}{\Delta} \cdot \frac{\delta(\theta,R)}{\delta N_{qp}}\right]} \left(1 + \omega^2 \tau_r^2\right)^{1/2} \left(1 + \omega^2 \tau_{res}^2\right)^{1/2}$$



### M. Naruse et al. 2013 IEEE TST NEP 6 x 10^(-18) W/rHz

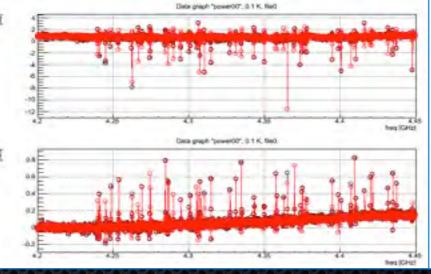
### 読出回路と0.1K希釈冷凍機

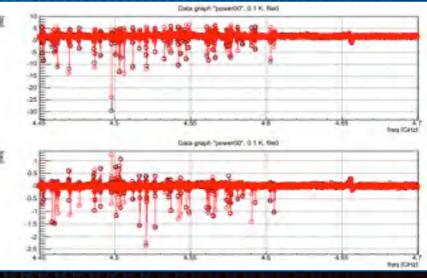




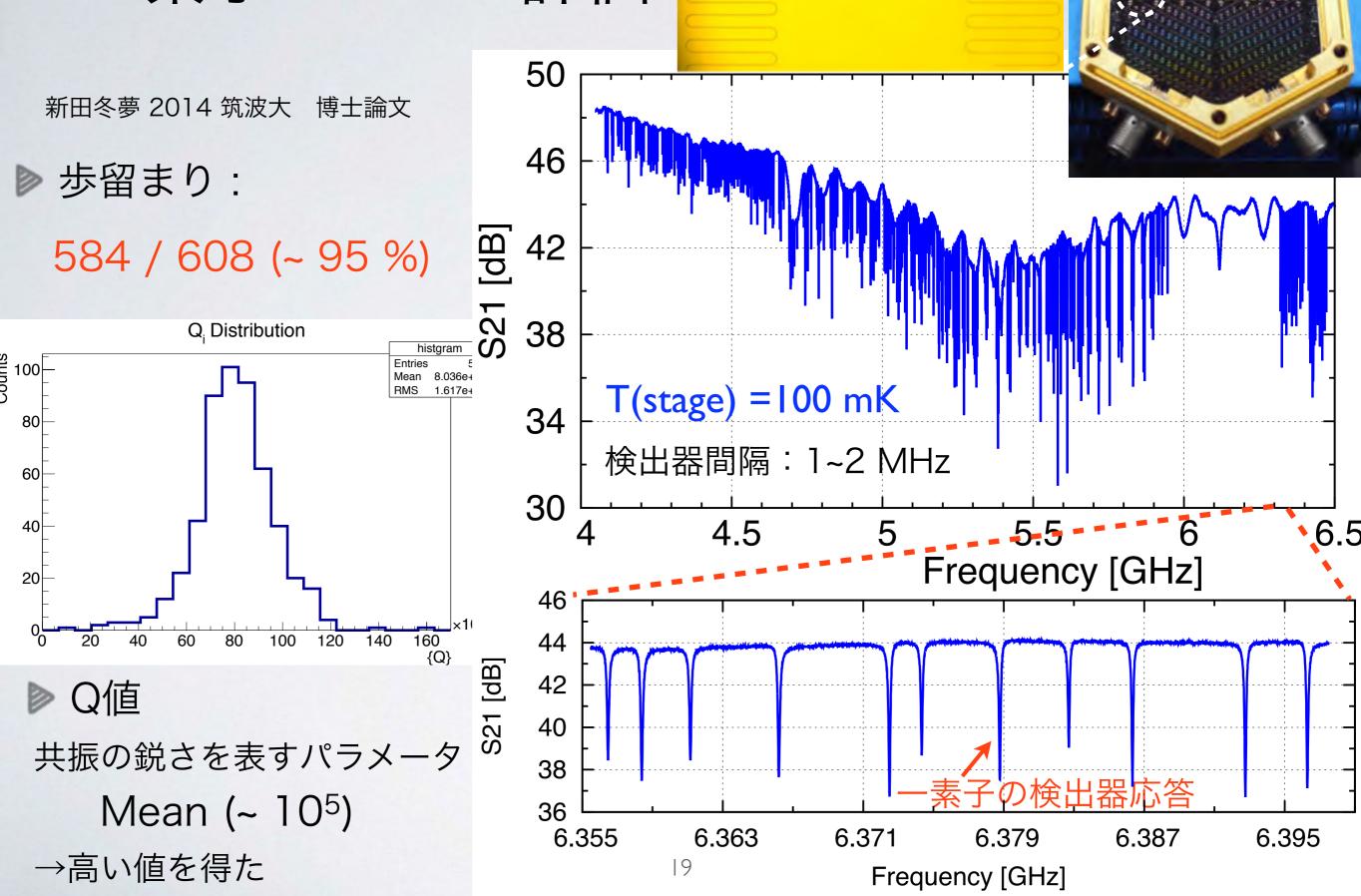
Readout 270 MHz/board → 1 GHz/board Resonator 2MHz spacing → 500 pixel/board 16 us sampling





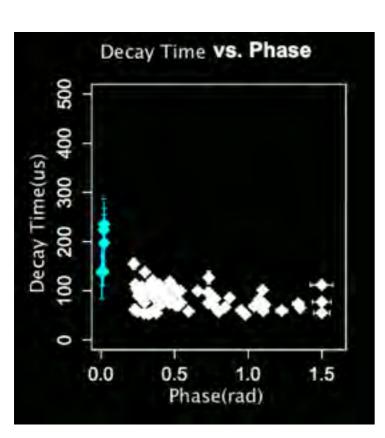


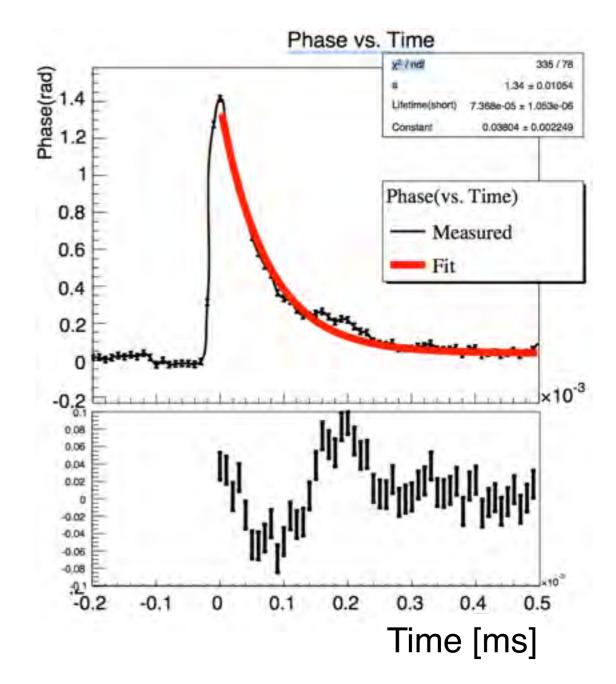
## 600素子MKIDの評価



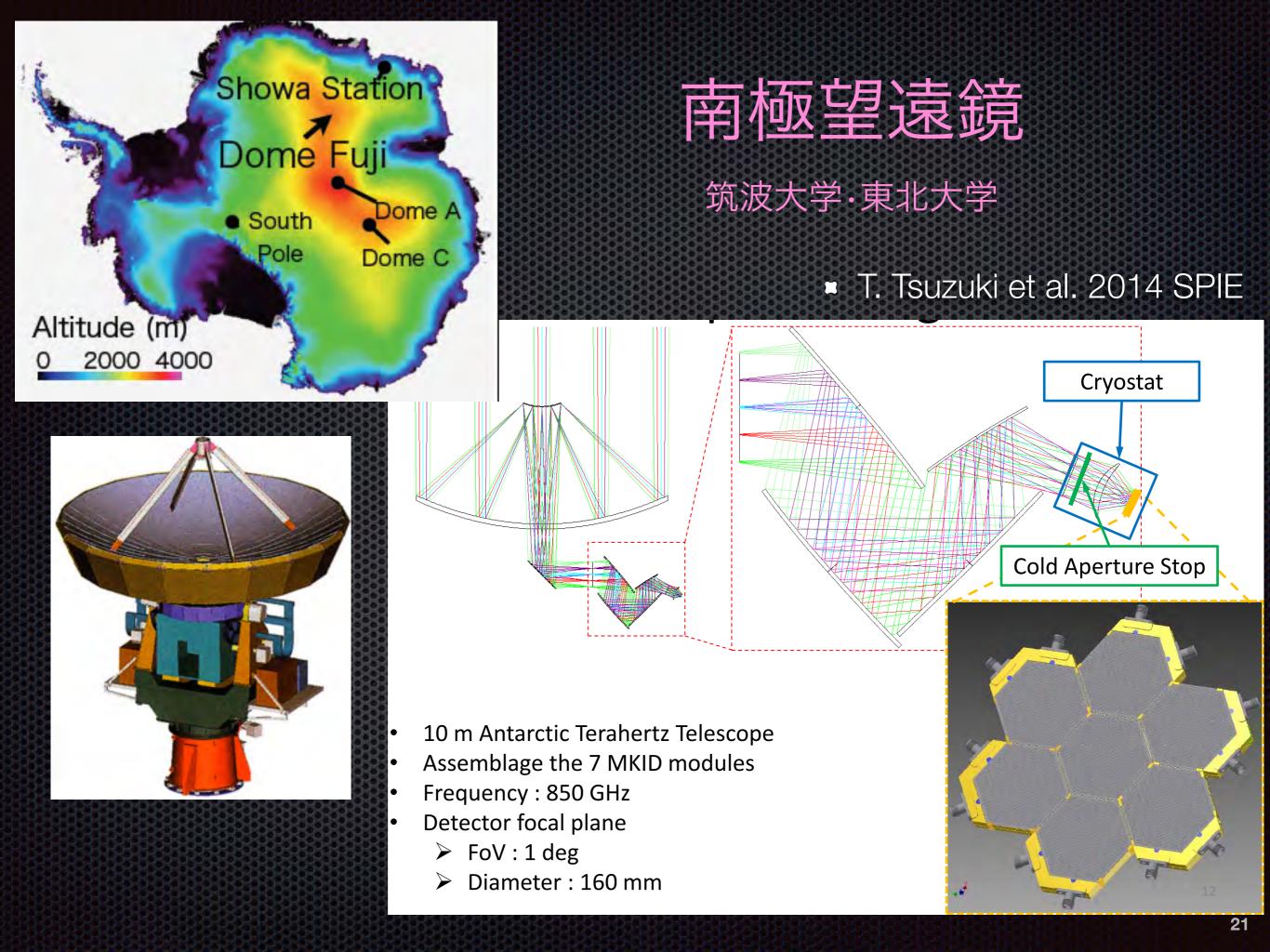
# Cosmic ray events

- $\cdot \tau = 79.9 \,\mu s$
- $\cdot \,$  a few events per an hour
- · T. Okada et al. 2014
- $\cdot$  1  $\mu$ s sampling





#### f=3.494GHz



# LiteBIRD

Lite (light) satellite for the studies of B-mode polarization and Inflation from cosmic background Radiation Detection

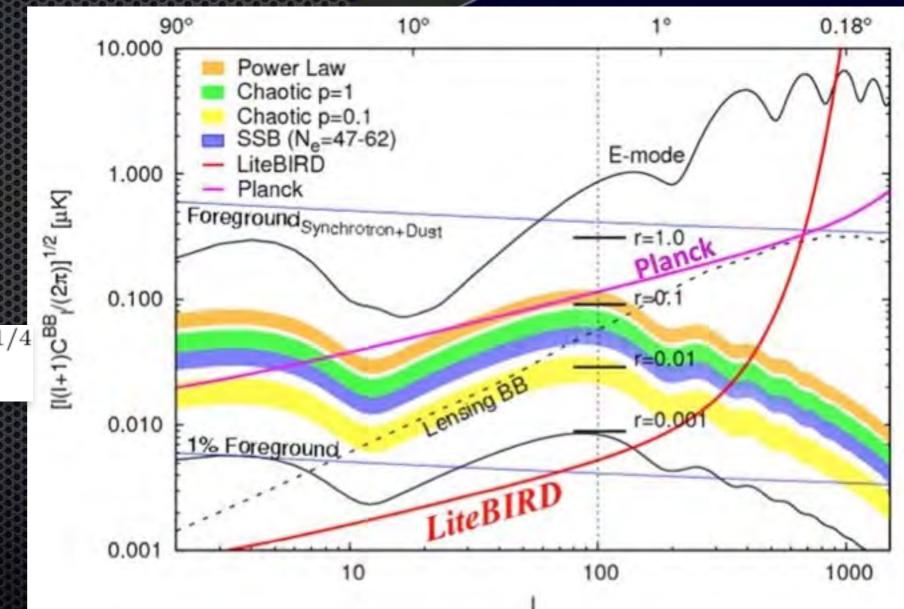
- 50 - 270 GHz ~ 600 pixel

E-mode

- Launch is planned in 2022
- KEK, ISAS/JAXA, U. Tokyo, NAOJ

**B-mode** 

- M. Hazumi et al. 2012 SPIE



Inflation potential energy

$$V^{1/4} = 1.1 \times 10^{16} \text{GeV} \left(\frac{r}{0.01}\right)^{1/4}$$

r: tensor to scalar ratio

## **Options for Higher efficiency**

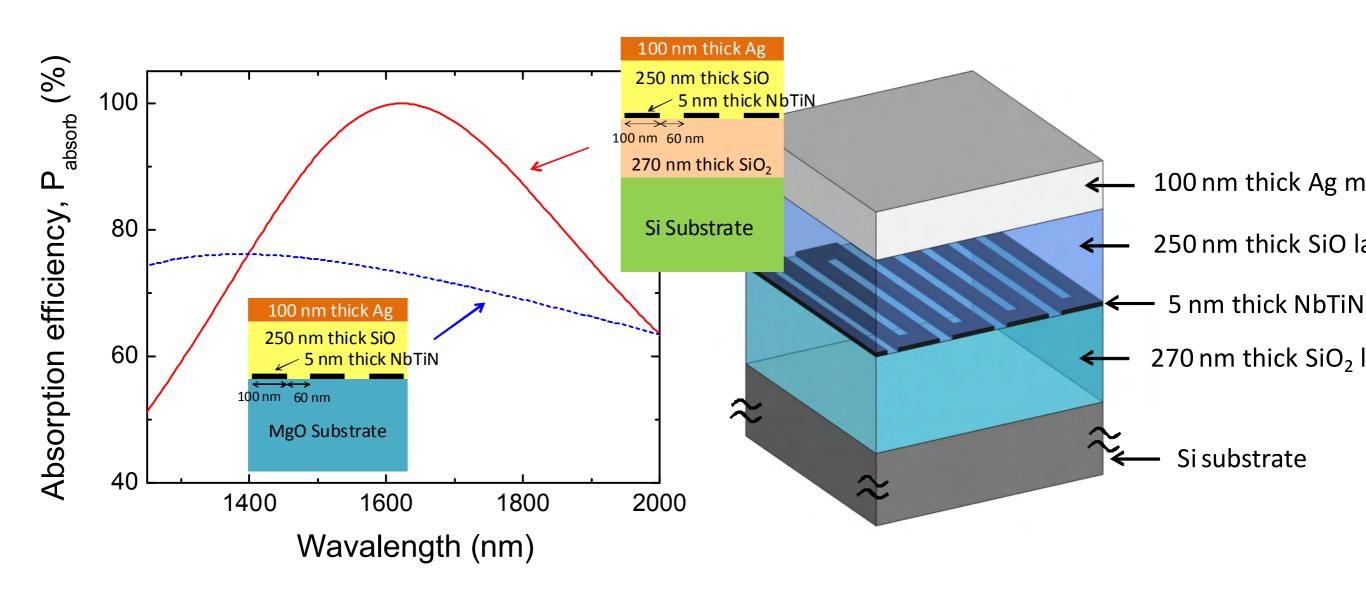
### 1. Optical Cavity

 S. Miki, et al. 2013 "High performance fiber-coupled NbTiN superconducting nanowire single photon detectors with Gifford-McMahon cryocooler.," Opt. Express, 21, 10208

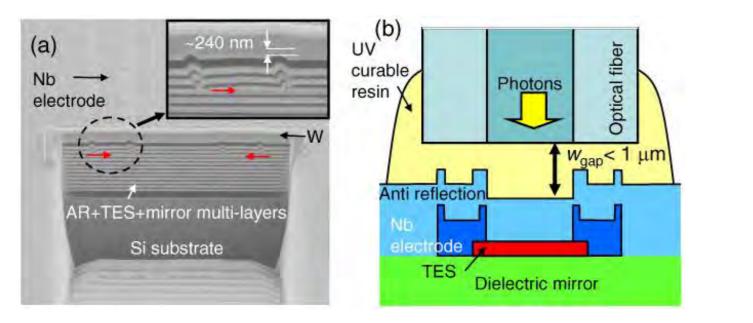
#### 2. Multilayer AR

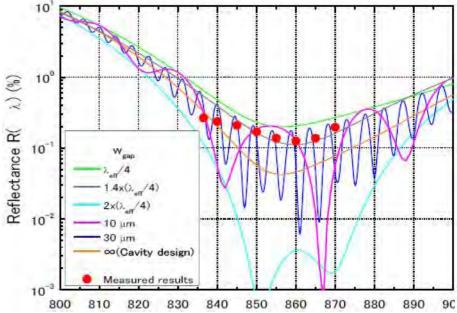
- Fukuda, D. et al., 2011 "Titanium-based transition-edge photon number resolving detector with 98% detection efficiency with index-matched small-gap fiber coupling.," Opt. Express 19(2), 870
- 3. New Material
  - · WSi
  - · Ta based superconductor

S. Miki, et al. 2013 "High performance fiber-coupled NbTiN superconducting nanowire single photon detectors with Gifford-McMahon cryocooler.," Opt. Express, 21, 10208–14



Fukuda, D. et al., 2011 "Titanium-based transition-edge photon number resolving detector with 98% detection efficiency with index-matched small-gap fiber coupling.," Opt. Express 19(2), 870



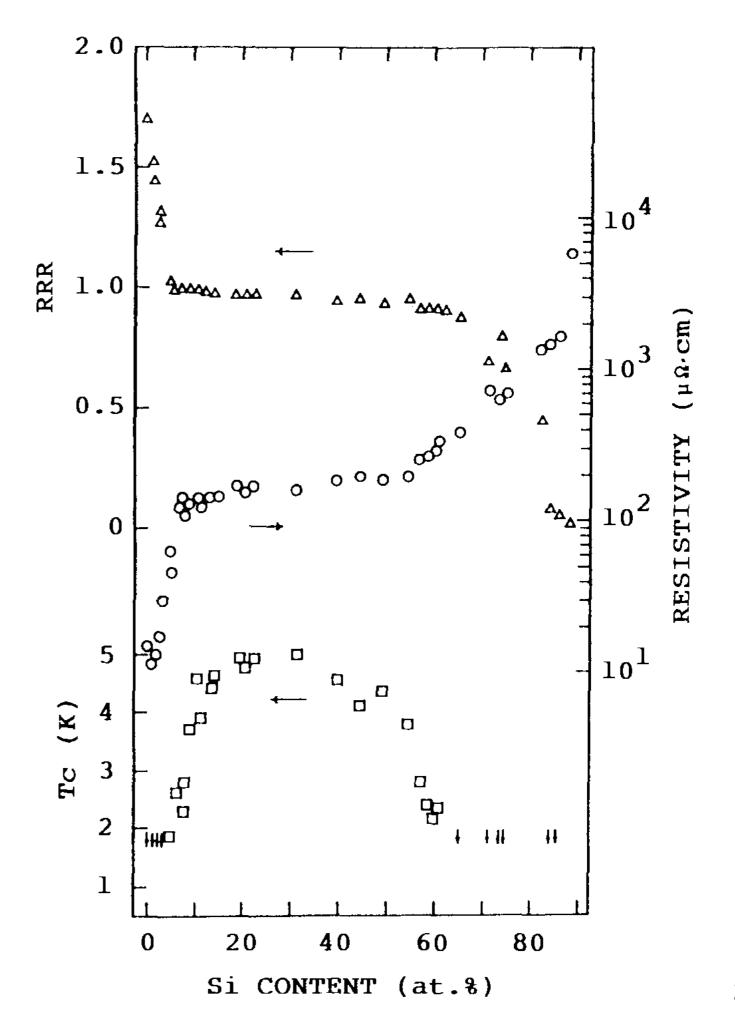


 $P_{Poisson}(n \mid \mu_i) = (\eta \mu_i)^n \exp(-\eta \mu_i) / n!$ 

### WSi

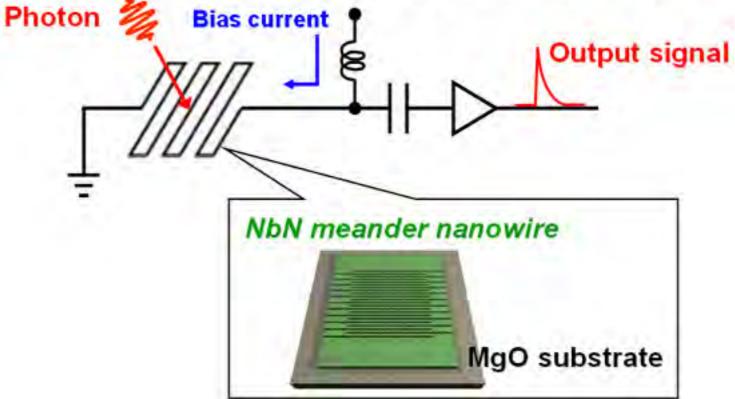
- Tungsten-Silicon
- Tc (W) = 10 mK
- 150 μΩ-cm
- low-pressure chemical vapor deposition (LPCVD) using tungsten hexafluoride (WF6) and silane (SiH4).

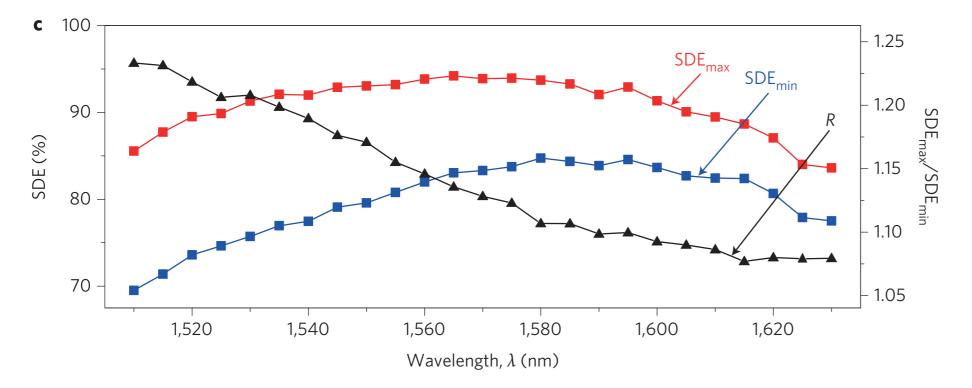
S. Kondo, 1991 "Superconducting characteristics and the thermal stability of tungsten-based amorphous thin films," J. Mater. Res., 7, 853



### WSi SSPD

Superconducting Single Photon Detector (SSPD)



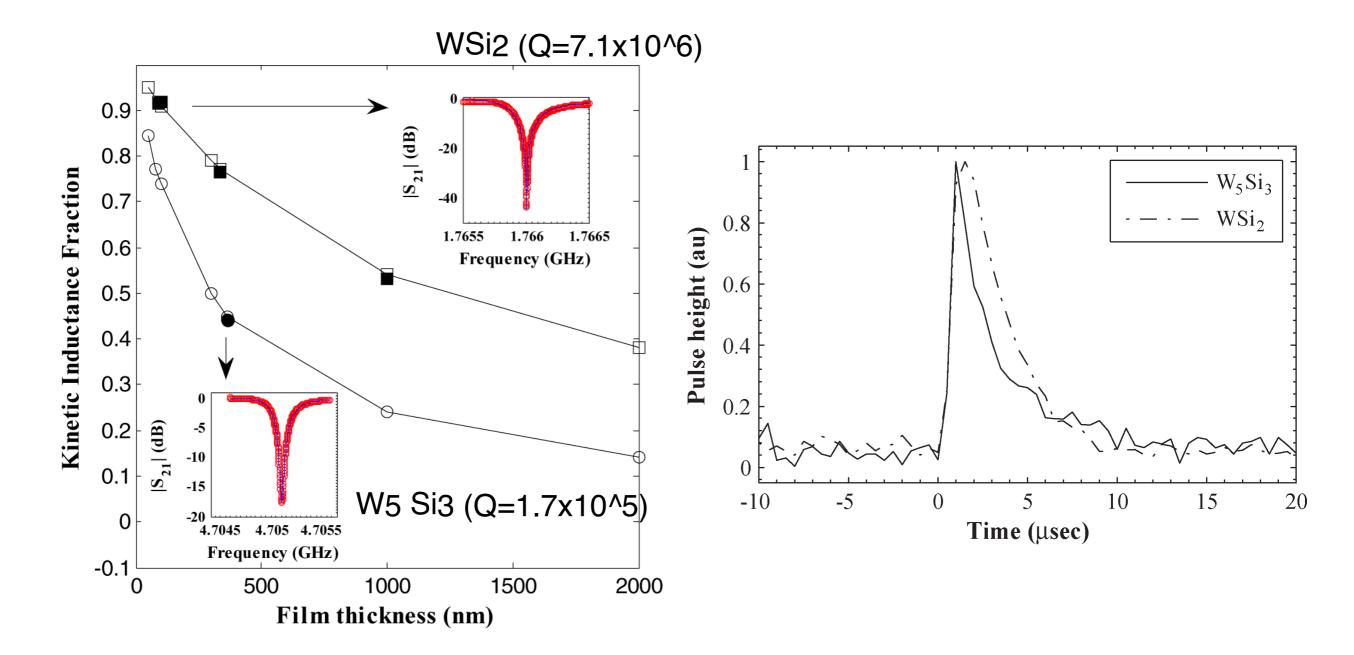


the WSi film was deposited by cosputtering W and Si targets1, or by sputtering a W0.55Si0.45 target, onto the substrate at room temperature.

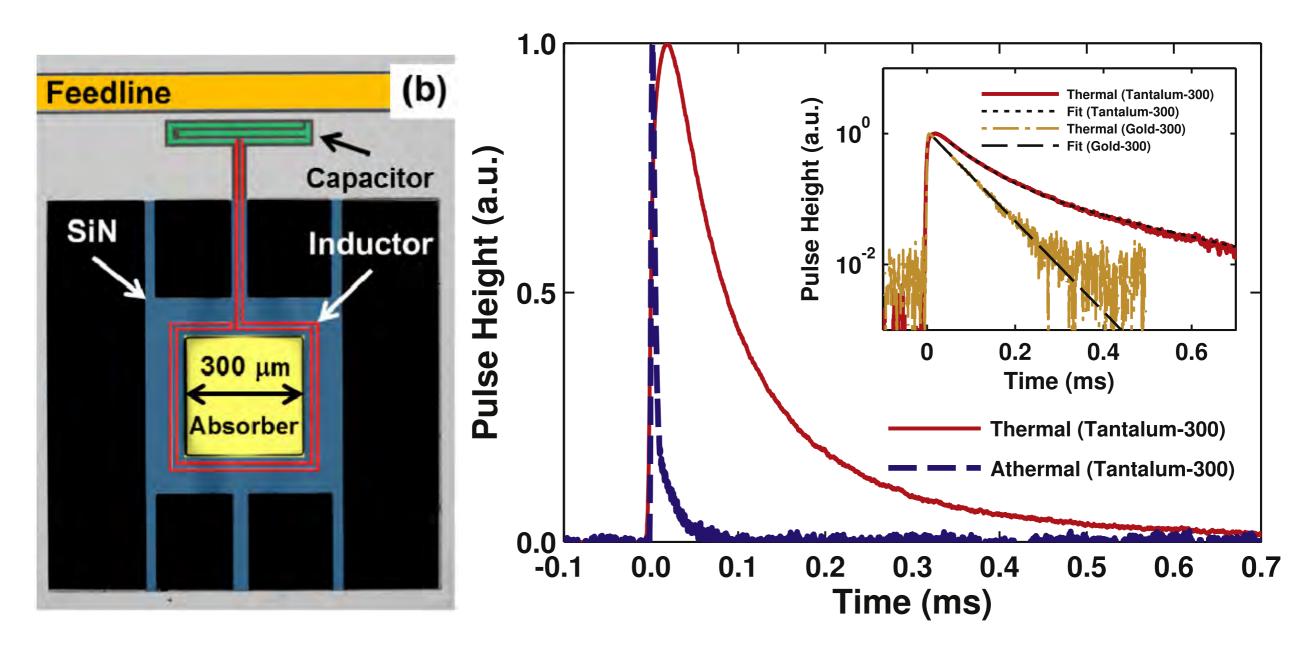
F. Marsili, et al. 2013 "Detecting single infrared photons with 93% system efficiency," Nat. Photonics, 7, 210

O. Quaranta, T. W. Cecil, and A. Miceli, 2013 "Tungsten Silicide Alloys for Microwave Kinetic Inductance Detectors," IEEE Trans. Appl. Supercond., 23, 2400104.

W5 Si3 (Tc = 4K) and WSi2 (Tc = 1.9K). The films were deposited using DC magnetron sputtering from a single compound target onto both silicon and sapphire wafers.



O. Quaranta, et al. 2013, "X-ray photon detection using superconducting resonators in thermal quasi-equilibrium," Supercond. Sci. Technol., 26, 105021



a 100 nm thick WSi2 film (gray). The interdigitated capacitor (IDC) portion (green) is on solid SiN/Si substrate (500 nm/ 300 µm), while the inductive meander (red) lies on the suspended SiN membrane (blue). The meander encircles the absorber (yellow).

超伝導検出器 2014/12/4 Y. Sekimoto

### Resolution at 1.5 um

material	Тс	Tbath	fg	NIR resolution
	К	mK	GHz	at 1.5 um
NbN	16	2286	1168	13
NbTiN	14	2000	1022	14
Nb	9.3	1329	679	17
Nb/Al	7.0	1000	511	20
TiN	4.5	643	329	25
WSi	4.2	600	307	26
TiN	1.1	157	80	51
AI	1.2	171	88	48
Al/Ti	0.7	100	51	63
Ti	0.40	57	29	84

$$R = \frac{\lambda}{\Delta\lambda} = \frac{1}{2.355} \sqrt{\frac{\eta h\nu}{F\Delta}}$$

$$\eta = 0.57, \quad F = 0.2$$
 Fano factor



#### 超伝導検出器

- 会ミリ波サブミリ波
- 合わが必須
- MKIDは多ピクセル読み出しが容易
- ●近赤外•可視•紫外線
  - 🛞 低分散面分光
  - 高速読出
  - 会高い量子効率